Deferred Updates for Flash-based Storage

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Properties of Flash Memory

Asymmetric Read and Write Behavior

- In-Place-Update Problem
 - To overwrite a sector (page), entire block needs to be erased
- Wear Out Problem
 - Frequent erases of blocks reduces the lifetime of flash memory

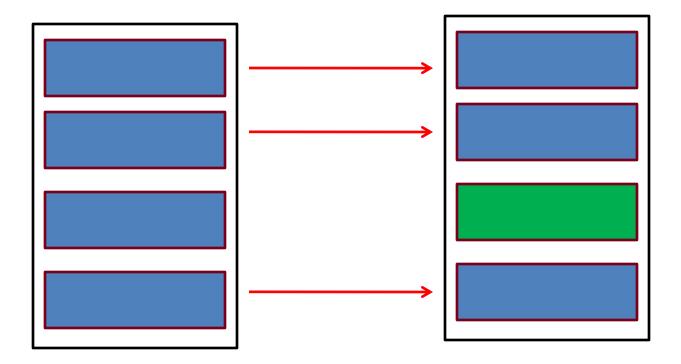


Problem Definition

- Given
 - Flash Memory Characteristics
 - Either DRAM is limited or data needs to flushed very frequently
- Design a new Update Processing Technique
 - Improve the update processing time and lifetime
 - For applications incurring lot of small random write operations



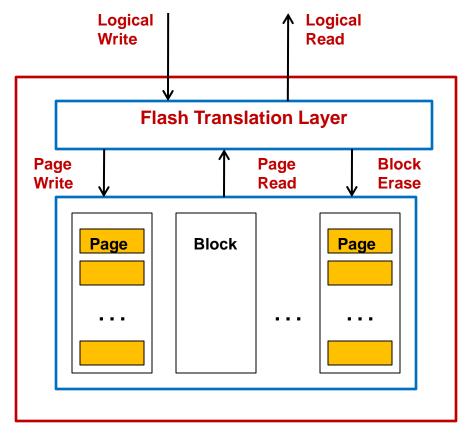
Over-Write in Flash Memory





Solid State Disk (SSD)

- Solid State Disks
 - Acts like a virtual HDD
 - NAND Flash-based
 - Faster read performance
 - Good sequential write performance
- Read/write in page units
- Erase in block units
- Must erase a **block** before write
- Typical block = 128K; page = 2K
- Read latency 25 microseconds
- Write latency 200 microseconds
- Erase latency 1500 microseconds
- Limited number of erases per block







Scope of This Work

- Flash-based devices having no FTL
 - Sensor motes
 - Windows Mobile OS
- Customized FTL
 - FPGA-based Reconfigurable FTL
 - Useful for the super-computing environment

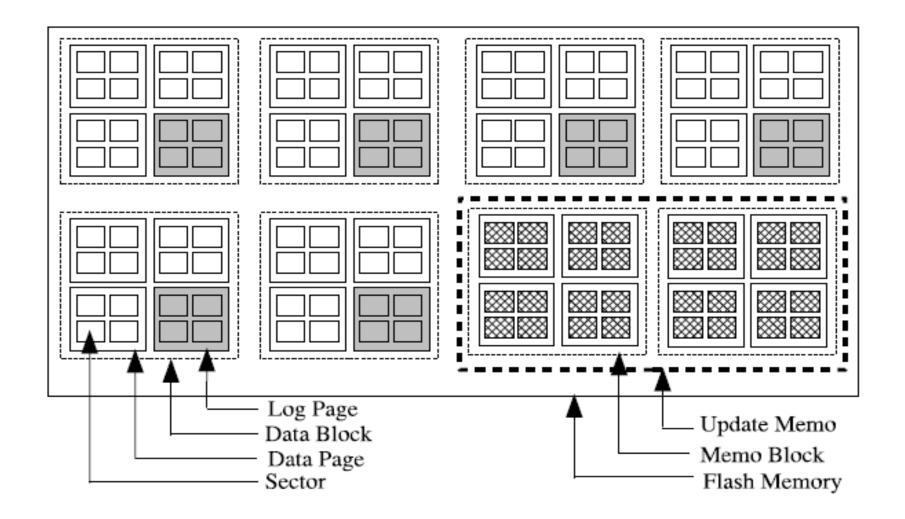


Main Idea

- Reduce the total number of expensive erase operations
- Defer the changes due to update operations as logs
 - A buffer-space is used to temporarily hold the logs
 - Apply multiple updates logs at once
- Part of flash memory is used as buffer-space
 - Buffer-space consists of *update memo and log page(s)*

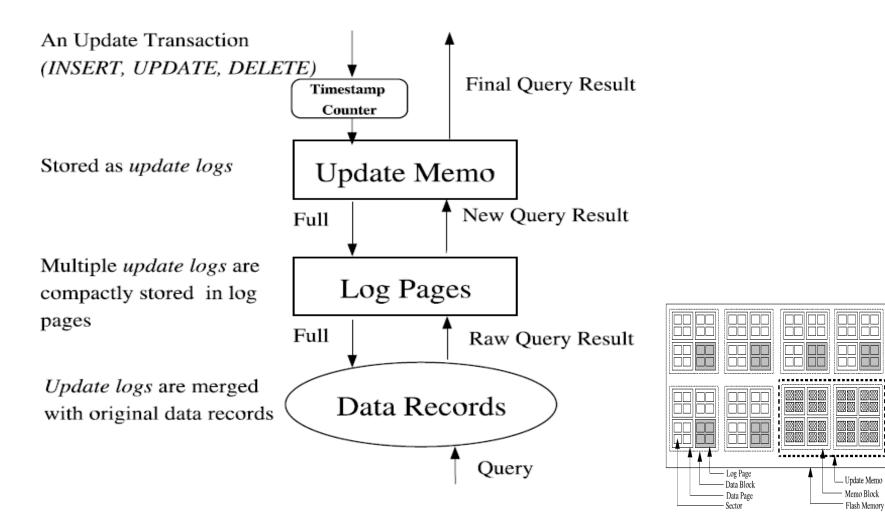


System Overview





Deferred Update Methodology





Thank You! Comments / Questions?

